

LOS R 5000 E 1



Recommended Maximum Ratings

- Diffused lens package
- Low current requirements
- High light output
- Reliable and rugged
- IC. compatible

Reverse voltage	5.0V
D.C. forward current	30mA
Pulse current (10% duty cycle 0.1ms pulse width)	100mA
Operating temperature range	-25°C to +85°C
Storage temperature range	-25°C to +100°C
Lead soldering temperature (1.6mm from body)	+260°C for 5 secs.

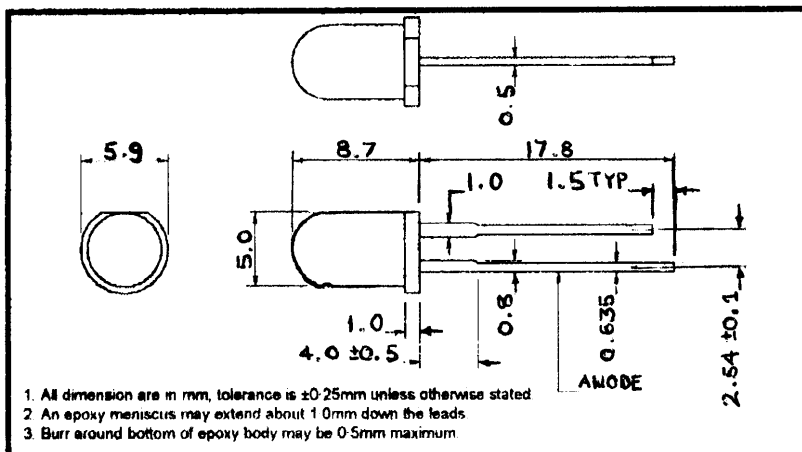
(Ta=25°C)

Electrical & Optical Characteristics

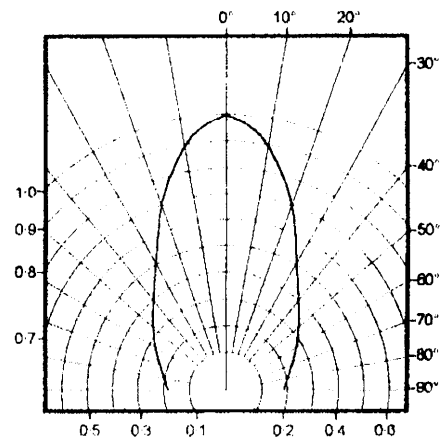
Part Number	L.E.D. Chip		Lens Colour	Peak Wavelength @20mA(nm)	Forward Voltage @20mA(V)		Luminous Intensity @10mA(mcd)		View Angle 2θ ½ (deg)
	Material	Emitting Colour			TYP.	MAX.	MIN.	TYP.	
L 02 R 5000 E 1	GaP	Green	Green Diffused	567	2.1	3.0	1.5	3.7	68°
L 02 R 5000 E 2	GaP	Green	White Diffused	567	2.1	3.0	1.5	3.7	68°
L 03 R 5000 E 1	GaAsP on GaP	Yellow	Yellow Diffused	585	2.1	3.0	1.2	3.1	68°
L 03 R 5000 E 2	GaAsP on GaP	Yellow	White Diffused	585	2.1	3.0	1.2	3.1	68°
L 04 R 5000 E 1	GaAsP on GaP	Orange	Orange Diffused	635	2.1	3.0	1.7	4.3	68°
L 04 R 5000 E 2	GaAsP on GaP	Orange	White Diffused	635	2.1	3.0	1.7	4.3	68°
L 4R R 5000 E 1	GaAsP on GaP	Hi-Eff. Red	Red Diffused	635	2.1	3.0	1.7	4.3	68°
L 05 R 5000 E 1	GaP	Red	Red Diffused	700	2.1	3.0	0.3	0.8	68°
L 05 R 5000 E 2	GaP	Red	White Diffused	700	2.1	3.0	0.3	0.8	68°

(Ta=25°C)

Package Dimensions

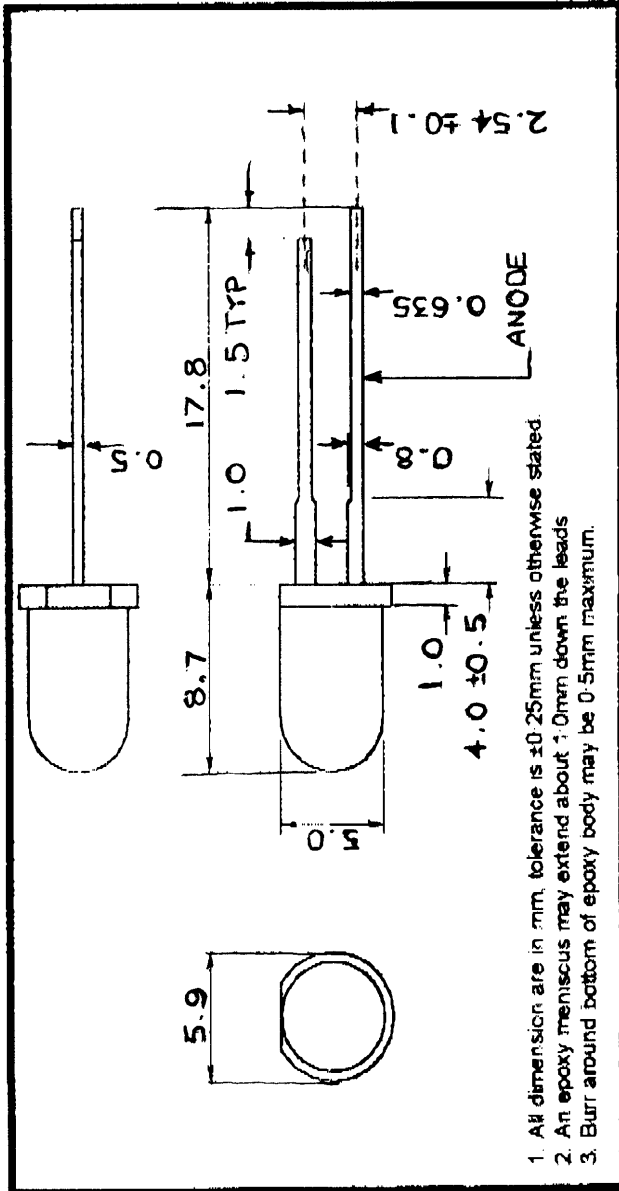


Radiation Pattern



Package Dimensions

L05R5000E1



1. All dimension are in mm, tolerance is ±0.25mm unless otherwise stated.
2. An epoxy meniscus may extend about 1.0mm down the leads
3. Burr around bottom of epoxy body may be 0.5mm maximum.

Radiation Pattern

